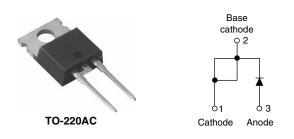
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Ultrafast Rectifier, 15 A FRED Pt[®]



PRODUCT SUMMARY									
Package	TO-220AC								
I _{F(AV)}	15 A								
V _R	1200 V								
V _F at I _F at 125 °C	2.25 V								
t _{rr}	44 ns								
T _J max.	175 °C								
Diode variation	Single die								

FEATURES

- · Ultrafast and soft recovery time
- Optimized forward voltage drop
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Rugged design
- · Good thermal performance
- Meets JESD 201 class 2 whisker test
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, recovery time, and soft recovery. Polyimide passivated, planar structure and the platinum doped life time control guarantee, ruggedness, reliability characteristics, and solid value proposition for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery charger, inverters of solar inverters, or as freewheeling diodes in motor drive.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Repetitive peak reverse voltage	V _{RRM}		1200	V						
Average rectified forward current	I _{F(AV)}	T _C = 115 °C, D = 0.50	15							
Non-repetitive peak surge current	I _{FSM}	$T_C = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	150	А						
Repetitive peak forward current	I _{FRM}		30							
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	MIN.	TYP.	MAX.	UNITS						
Breakdown voltage, blocking voltage	V _{BR} , V _R	$I_{\rm D} = 250 \text{UA}$		-	-					
Forward voltage	V _F	I _F = 15 A	-	2.3	2.78	V				
		I _F = 15 A, T _J = 125 °C	-	2.25	2.7					
Reverse leakage current		$V_R = V_R$ rated	-	-	80					
neverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	150	μA				
Junction capacitance	CT	V _R = 200 V	-	13	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH				

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RoHS

COMPLIANT HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)											
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS				
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 10$	00 A/µs, V _R = 30 V	-	44	-					
Reverse recovery time	t _{rr}	T _J = 25 °C		-	167	-	ns				
		T _J = 125 °C		-	248	-					
Pools recovery ourrent	I _{RRM}	$T_J = 25 \ ^\circ C$	I _F = 15 A dI _F /dt = 100 A/µs	-	6	-	А				
Peak recovery current		T _J = 125 °C	$V_{\rm R} = 390 \text{ V}$	-	9	-					
Devenue versione also vers	_	$T_J = 25 \ ^\circ C$		-	507	-	nC				
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1110	-	ne				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction to case	R _{thJC}		-	1.1	1.3					
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	54	60	°C/W				
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	0.4					
Waight			-	0.2	-	g				
Weight			-	0.07	-	oz.				
Mounting torgue			6.0	_	12	kgf · cm				
Mounting torque			(5.0)		(10)	(lbf ⋅ in)				
Marking device		Case style: TO-220AC	15ETU12							
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				

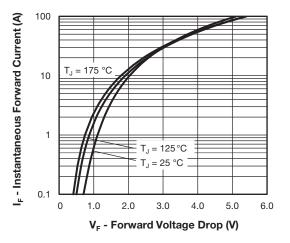


Fig. 1 - Typical Forward Voltage Drop Characteristics

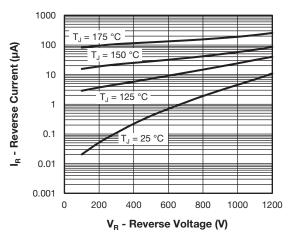


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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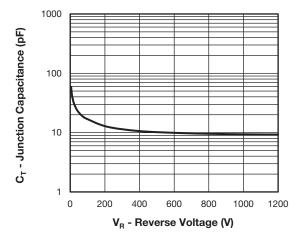


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

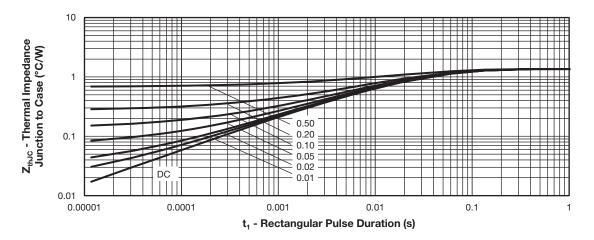


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

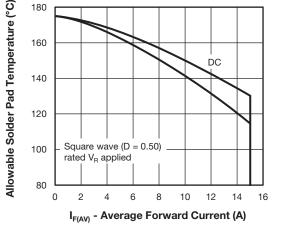


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

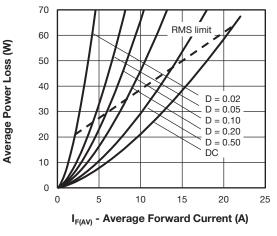


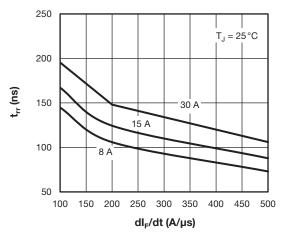
Fig. 6 - Forward Power Loss Characteristics

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Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

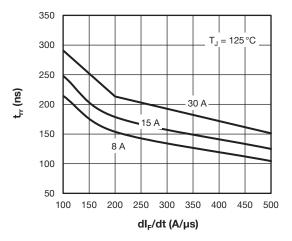


Fig. 8 - Typical Reverse Recovery Time vs. dI_F/dt

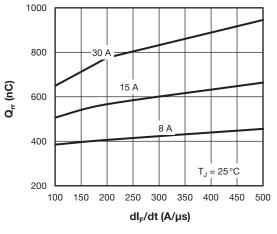


Fig. 9 - Typical Stored Charge vs. dl_F/dt

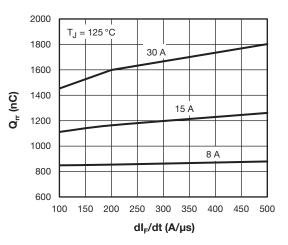
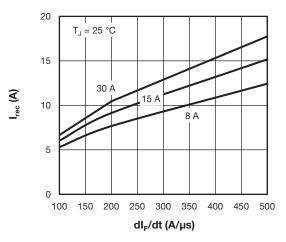


Fig. 10 - Typical Stored Charge vs. dl_F/dt





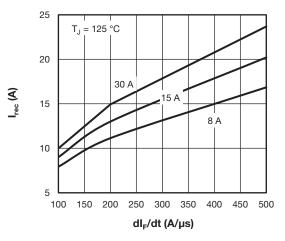


Fig. 12 - Typical Reverse Current vs. dl_F/dt

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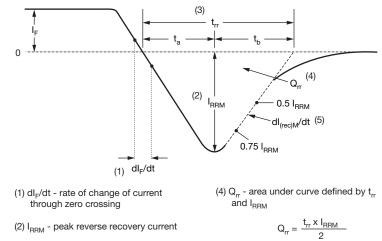
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VS-15ETU12-N3

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(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 $\mathrm{I}_{\mathrm{RRM}}$ and 0.50 $\mathrm{I}_{\mathrm{RRM}}$ extrapolated to zero current.

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

www.vishay.com

Device code	VS-	15	Е	т	U	12	-N3	
		(2)	(3)	(4)	(5)	(6)	(7)	I
	1 -	Visł	nay Sem	niconduc	ctors pro	oduct	_	
	2 -			ng (15 = 	15 A)			
	3 - 4 -		single c kage:	liode				
	4		TO-220	I				
	5 -	U =	ultrafas	t recove	ery			
	6 -	Volt	age rati	ng (12 =	= 1200 ∖	/)		
	7 -	Env	rironmer	ntal digit	:			
		-N3	= halog	en-free	RoHS-	complia	ant, and	totally le

ORDERING INFORMATION (Example)									
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION									
VS-15ETU12-N3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?95221							
Part marking information	www.vishay.com/doc?95068							

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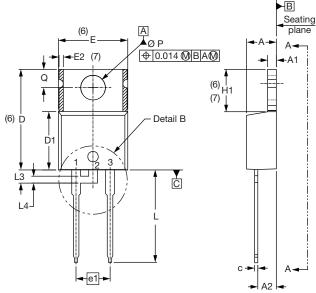


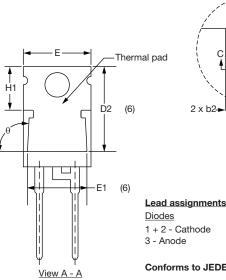
TO-220AC

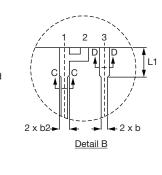
plane

A-

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIM	IETERS	INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STNIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOILS
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040			e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4		H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068			L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4		L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024			L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4		L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6		θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6							

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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